## **Technical Program Contents**

#### **Session A**

**Ziegfeld Room: Opening Ceremony** 

8:30 a.m. - 10:00 a.m.

Tuesday, June 9, 1987

Welcome

Mr. Steve March Dr. Dave McQuiddy

Dr. Rey Kagiwada

**Keynote Address** 

Mr. Les Besser

## **Session B**

## Ziegfeld Room: Joint with Monolithics Symposium - Non-Linear and Power Circuits

Chairman: D.R. Chen, Microwave Monolithics, Inc.

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Tuesday, June 9, 1987

	Co-Chairman: Z.J. Lemnios, Ford Microelectronics, Inc.	
B-1 10:30 a.m.	Nonlinear Modeling for MMICs (Invited) Don Estreich Hewlett-Packard, Microwave Technology Division, Santa Rosa, CA	85
B-2 11:00 a.m.	Ka-Band Monolithic GaAs Power FET Amplifiers H.L. Hung, A. Ezzeddine, L. Holdeman, F. Phellips, J. Allison, A. Cornfeld, T. Smith, and H. Huang Comsat Laboratories, Clarksburg, MD.	89
B-3 11:20 a.m.	Wideband GaAs MMIC Receiver D.C. Yang, R. Estandiari, T.S. Lin and T. O'Neill TRW Inc., Microwave and Millimeter-Wave Technology Center Redondo Beach, CA	93
B-4 11:40 a.m.	1-6 GHz GaAs MMIC Linear Attenuator with Integral Drivers T. Andrade, G. Lazama, R. Benton Pacific Monolithics, Inc. Sunnyvale CA	97

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### Gable 5, 6, 7 Room: Computer-Aided Design Analysis and Synthesis 10:30 a.m. to Noon Tuesday, June 9, 1987

Chairman: Ulrich L. Rohde, Compact Software

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C-3 10:50 a.m.	Optimum Design of Non Linear Power FET Amplifiers C. Guo*, M. Camiade**, D. Rousset*, A. Cessey**, J. Obregon*, and A. Bert** *IRCOM Université de Limoges, France **Thomson Composants DHM, Massy, France	111
C-4 11:10 a.m.	Generalized Power Series Analysis of Intermodulation Distortion in a MESFET Amplifier: Simulation and Experiment G.W. Rhyne and M.B. Steer Department of Electrical and Computer Engineering North Carolina State University, Raleigh, NC	115
C-5 11:30 a.m.	The Spectral Balance: A General Method for Analysis of Nonlinear Microwave Circuits Driven by Non-Harmonically Related Generators M. Gayral, E. Ngoya, R. Quere, J. Rousset, J. Obregon Université de Limoges, France	119
C-6 11:50 a.m.	Modeling of Circular Spiral Inductors for MMICs I. Wolff Dept. of Elect. Engr. Duisburg University, FRG. and H. Kapusta, Siemens AG, Munchen, FRG.	123

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# Gable 3, 4 Room: Microwave Filters and Multiplexers 10:30 a.m. to Noon Tuesday, June 9, 1987

Chairman: R.V. Snyder, R.S. Microwave Company, Inc.

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D-4 11:20 a.m.	Dual Mode Dielectric Resonator Filters Without Iris K.A. Zaki and C. Chen Electrical Engineering Department University of Maryland College Park, MD A.E. Atia Comsat Corporation, 950 L'Enfant Plaza S.W. Washington, DC	141
D-5 11:30 a.m.	Quadruple-Mode Filters R.R. Bonetti and A.E. Williams Comsat Laboratories Clarksburg, MD	145
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Co-Chairman. S. Woghe, Lacine Woholithes	
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C. Yuen, and G. Zdasiuk Varian Research Center, Palo Alto, CA	
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K.G. Wang and S.K. Wang Hughes Aircraft Company Torrance, CA	
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Laboratoires D'Electronique Et De Physique Appliqué

Limeil-Brevannes, France

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	Western Development Laboratories Palo Alto, CA	
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Chairman: Peter LaTourette, Consultant

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Chairman: Arye Rosen, RCA David Sarnoff Research Center

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	Royal Military College of Science, Shrivenham, UK	
	A.W. Preece	
	Royal Infirmary, Bristol, UK	
	J.W. Hand	
	Hammersmith Hospital, London, UK	
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	Institute of High Frequency Technique	
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	MIT	
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	X. Deming, L. Liping and J. Zhiyan	
	Department of Radio & Electronics	
	Shanghai University of Science & Technology	
	Shanghai, P.R. China	
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	David Sarnoff Research Center, Princeton, NJ	
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### Ziegfeld Room: MMW Technology and Applications 8:30 a.m. to 10:00 a.m. Wednesday, June 10, 1987

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Dept. of Chemical Engineering

\*Dept. of Electrical Engineering & System Science,

Michigan State University, East Lansing, MI

## **Session M**

#### Gable 3, 4 Room: Communications Systems

8:30 a.m. to 10:00 a.m.

Wednesday, June 10, 1987

Chairman: Peter G. Petrelis, TRW

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#### **Session N**

#### Ziegfeld Room: - Focused Session -

#### Advances in Millimeter Wave Systems (60-230 GHz)

#### 10:30 a.m. to Noon

Wednesday, June 10, 1987

Chairman: James C. Wiltse, Georgia Tech Research Institute

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## **Session O**

#### Gable 5, 6, 7 Room: Noise Measurements

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Wednesday, June 10, 1987

Chairman: Stephen F. Adam, Adam Microwave Consulting, Inc.

0-1	A New Measurement System for Oscillator Noise	
10:30 a.m.	Characterization	509
	A.N. Riddle	
	Avantek Inc.	
	Milpitas, CA	
	and R.J. Trew	
	North Carolina State University	
	Raleigh, NC	
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	M.S Gupta*, O. Pitzalis, Jr., S.E. Rosenbaum and P.T. Greiling	
	Hughes Research Laboratories	
	Malibu, CA	
	*University of Illinois at Chicago	
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	V.A. Hirsch and T.H. Miers	
	Ball Aerospace Systems Division	
	Boulder, CO	
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	Dept. of Electrical and Electronic Engineering	
	University of Leeds, UK	
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11:40 a.m.	P. Tong, N. Fernandez, J. Gladstone and E. Cristal	
	Hewlett-Packard	
	Palo Alto, CA	

## **Session P**

### Gable 3, 4 Room: Radar Systems

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Wednesday, June 10, 1987

Chairman: Kiyo Tomiyasu, General Electric Co.

10:30 a.m.	Airport Beacon System Sensor  T.M. Nelson, M.J. Reinhart, K.J. Yoo, D.A. Poltorak and R.K. Palmer Westinghouse Electric Corp.  Baltimore, MD	531
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Q-2	A Comparative Study of TEGFET and MESFET Characteristics and Saturation Mechanisms M. Weiss Thomson Semiconductors, Orsay, France and D. Pavlidis University of Michigan, Ann Arbor, MI	Large Signal 553	
Q-3	Comparative Study of Phase Noise in HEMT and Microwave Oscillators M. Pouysegur LAAS du CNRS, Toulouse, France J. Graffeuil, J.F. Sautereau Université Paul Sabatier, Toulouse, France and J.P. Fortea Centre Nat. D'Études Spatiales, Toulouse, France	MESFET 557	
Q-4	A GaAs Monolithic 6 GHz Low-Noise Amplifier for Receivers R. Mott COMSAT Laboratories Clarksburg, MD	For Satellite 561	
Q-5	Miniature Gain Block for Satellite Communicatio A. Fathy, R. Brown and E. Belohoubek RCA Laboratories Princeton, NJ	n Transceivers 565	
Q-6	A GaAs Microwave MESFET with Extremely Lor G.G. Zhou, T. Curtis and R. Chen Gould Inc. Microwave Products Division San Jose, CA	w Distortion 569	
Q-7	The Deformable-Channel Model-A New Approach MESFET Modeling F. Crowne, A. Eskandarian, H.B. Sequeira and R. Martin Marieta Laboratories/Gamma Monolithics Baltimore, MD	573	

Q-8	Load-Line Analysis in the Frequency Domain with Distributed Amplifier Design Examples M.L. Salib, D.E. Dawson, and H.K. Hahn Westinghouse Electric Corp. Baltimore, MD	575
Q-9	Fast Settling, Low Noise Ku Band Fundamental Bipolar VCO A.P.S. Khanna Avantek Inc. Santa Clara, CA	579
Q-10	Long Term Stability of DROs Compared to Crystal Oscillators K.R. Varian Rockwell International Dallas, TX	583
Q-11	Low Phase Noise X/KU-Band VCO D.A. Boyd Eaton Corp., Microwave Products Division Sunnyvale, CA	587
Q-12	Microwave Resistance of Gallium Arsenide and Silicon P-I-N Diodes R. Caverly Southeastern Mass. University N. Dartmouth, MA and G. Hiller M/A-COM Semiconductor Products Burlington, MA	591
Q-13	W Band Crossbar Mixers Integrated Entirely on a Single-Sided Substrate Yielding 15 GHz Instantaneous Bandwidth S. Low COM DEV Ltd. Cambridge, Canada	595
Q-14	Diode Phase Shifter and Model in Waveguide J.A. Lester and C.M. Jackson TRW Redondo Beach, CA and K. Chang Texas A & M University, TX	599

Q-15	Wide-Band True Time Delay Phase Shifter Device P.R. Herczfeld, A. Daryoush Drexel University, Philadelphia, PA M. Kieli Thomas & Betts, Raritan, NJ S. Siegel RCA, David Sarnoff Lab, Princeton, NJ and R. Soref RACD/ESO Hanscom AFB, MA	603
Q-16	A Novel Whiskerless Schottky Diode for Millimeter and Submillimeter Wave Application W.L. Bishop, K. McKinney, R.J. Mattauch, T.W. Crowe, and G. Green Department of Electrical Engineering University of Virginia, Charlottesville, VA	607
Q-17	Filled Image Guide for Millimeter-Wave Circuits M.Q. Shi and D.H. Jiang Peking University Beijing, People's Republic of China	611
Q-18	A Tunable Grating Impedance Transformer J.D. Xu Northwestern Polytechnical University Xian Shaanxi, China	*
Q-19	A Novel Technique for Evaluation and Integration of Connectorless (Drop-In) Microwave Components D. Herstein General Microwave Corporation Amityville, NY	613
Q-20	Coupling Between Hybrid Mode Dielectric Resonators K.A. Zaki and C.M. Chen Electrical Engineering Department University of Maryland College Park, MD	617
Q-21	Exact Calculation of Scattering Parameters of the Coplanar  - Slot Transition in a Unilateral Finline Technology  O. Picon, J.P. Lefevre, V.F. Hanna  CNET, Issy-Les-Moulineaux, France  and J. Citerne  Laboratoires Structures Rayonnantes, Rennes Cedex, France	621

<sup>\*</sup>Manuscript not available at the time of printing

Q-22	Analysis of VLSI Interconnect Structures L. Carin, Q. Xu, and K. J. Webb University of Maryland College Park, MD and J.A. McClintock Martin Marietta Labs Baltimore, MD	625
Q-23	Towards a Unified Efficient Algorithm for Characterizing The Planar Periodic Waveguides K. Wu and P. Saguet Laboratoire D'Élelectromagnetisme Et Optique Guidée E.N.S.R.G. Grenoble, France	629
Q-24	Centering and Tolerancing the Components of Microwave Amplifiers  A. MacFarland, J. Purviance Department of Electrical Engineering University of Idaho Moscow, Idaho and D. Loescher, K. Diegert, and T. Ferguson Sandia National Laboratories Albuquerque, NM	633
Q-25	Analysis of Discontinuities in Optical Waveguides J.B. Davies and B.M.A. Rahman University College London, UK	637
Q-26	Optical Crosstalk Due to Electrical Coupling in High Speed LINb03  P. Perlmutter, J.E. Baran and Y Silberberg Bell Communications Research Red Bank, NJ	641
Q-27	Optoelectronic Generation and Sensing of Millimeter Waves A.P. DeFonzo and C. Lutz University of Massachusetts Amherst, MA	645
Q-28	Generation of Kilowatt/Kilovolt Broadband Microwave Bursts with a Single Picosecond Photoconductive Switch H.A. Sayadian, M.G. Li and C.H. Lee University of Maryland College Park MD	649

Q-29	Large Signal Modulation of Semiconductor Lasers with Optical Feedback for Millimeter Wave Applications V.M. Contarino Naval Air Development Center Warminster, PA and A.S. Dayoush and P.R. Herczfeld Drexel University Philadelphia, PA	653
Q-30	Optically Controlled Millimeter Wave Phase Shifter in a Metallic Waveguide G. Hadjicostas and J. Butler Southern Methodist University Dallas, TX and M. Scott LTV Aerospace & Def. Co. Dallas, TX	657
Q-31	A New Generalised Approach to the Design of Microwave Oscillators Y. Xuan and C.M. Snowden Department of Electrical & Electronic Engineering University of Leeds Leeds, UK	661
Q-32	A Refractory Self-Aligned Gate Process for Monolithically Combined Microwave and Digital GaAs ICs  A. Geissberger, R. Sadler, E. Griffin, H. Singh, I. Bahl and M. Drinkwine ITT Gallium Arsenide Technology Center Roanoke, VA	665
Q-33	Analysis of Multiple-Step Radial-Resonator Waveguide Diode Mounts with Application to IMPATT Oscillator Circuits B.D. Bates Department of Electrical and Electronic Engineering University of Melbourne Australia	669
Q-34	Absorbed Power Distribution in Heart Lung System Due to Microwave Irradiation at 750 MHz J. Behari School of Environmental Sciences Jawaharlal Nehru University New Delhi, India	673

Q-35	Dielectric-Resonator-Stabilized Second Harmonic Ka-Band Microstrip Gunn Oscillator S. Zhong-Liang and C. Ning Department of Radio Engineering Nanjing Institute of Technology Nanjing, China	677
Q-36	Edge Corrections for Microstrip Planar Analysis Models H.A. Burger Goodyear Aerospace Corporation Litchfield Park, AZ	681
Q-37	Characterization Method and Simple Design Formulas of MCS Lines Proposed for MMICs E. Yamashita, K.R. Li, E. Kaneko, and Y. Suzuki University of Electro-Communications Tokyo, Japan	685
Q-38	Global Stability Analysis of Microwave Circuits by a Frequency-Domain Approach V. Rizzoli Department Di Electronica University of Bologna Bologna, Italy A. Neri Fondazione Ugo Bordoni Bologna, Italy	689
Q-39	Analysis Equations for Shielded Suspended Substrate Microstrip Line and Broadside-Coupled Stripline Y. Shu, X. Qi, Y. Wang Department of Radio Engineering Nanjing Institute of Technology Nanjing, China	693
Q-40	The Effectiveness of Four Direct Search Optimization Algorithms R.W. Rhea Scientific Atlanta, Inc. Atlanta, GA	697
Q-41	Computer Aided Design Models for Unilateral Finlines with Finite Metallization Thickness and Arbitrarily Located Slot Widths P. Pramanick, R.R. Mansour COM DEV Ltd. Cambridge, Canada and R.H. MacPhie University of Waterloo Ontario, Canada	703

Q-42	Puff, an Interactive Microwave Computer Aided Design Program for Personal Computers R.C. Compton, W.L. Williams, and D.B. Rutledge Division of Engineering and Applied Science California Institute of Technology Pasadena, CA	707
Q-43	An Automatic Decomposition Technique for Device Modeling and Large Circuit Design J.W. Bandler and Q.J. Zhang Electrical Engineering Department McMaster University Hamilton, Canada	<b>70</b> 9
Q-44	Modeling the Dispersion in a Suspended Microstripline R.S. Tomar Bolriet Technologies, Inc. Carleton Place, Ontario, Canada and P. Bhartia Department of National Defense Ottawa, Ontario, Canada	713
Q-45	An Almost-Periodic Fourier Transform for Use with Harmonic Balance K.S. Kundert, G. Sorkin and A. Sangiovanni-Vincentelli University of California Berkeley, CA	717
Q-46	Generalized Analysis of E-Plane Septa Discontinuities A. Rong, S. Li Nanjing Institute of Technology Nanjing, China	721

## **Session R**

## Gable 5, 6, 7 Room: Guided Waves

1:30 p.m. to 3:00 p.m	1:30	p.m.	to	3:00	p.m
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Wednesday, June 10, 1987

Chairman: Prof. Jeffrey B. Knorr, Naval Postgraduate School

R-1 1:30 p.m.	Simple Analytic Formulas for Dielectric Waveguides S.T. Peng New York Institute of Technology Old Westbury, NY S.L. Wang University of New Haven West Haven, CT F.K. Schwering U.S. Army CECOM Ft. Monmouth, NJ	727
R-2 1:50 p.m.	Guidance and Leakage Properties of Offset Groove Guide H. Shigesawa, M. Tsuji Doshisha University Koyoto, Japan A.A. Oliner Polytechnic University Brooklyn, NY P. Lampariello, F. Frezza University of Rome "La Sapienza" Rome, Italy	731
R-3 2:10 p.m.	Analysis and Design of Microslab™ Waveguide B. Young and T. Itoh University of Texas Austin, TX	735
R-4 2:30 p.m.	Microstrip Circuit Elements on Cylindrical Substrates A. Nakatani Phraxos Research and Development Inc. Santa Monica, CA and N.G. Alexopoulos University of California Los Angeles, CA	739
R-5 2:50 p.m.	Analysis of Double-Layered Finlines Containing a Magnetized Ferrite M. Geshiro On Leave From Ehime University, Ehime, Japan and T. Itoh University of Texas Austin, TX	743

#### **Session S**

#### Ziegfeld Room: - Focused Session -

### Advances in Millimeter Wave Technology (60-230 GHz)

1:30 p.m. to 3:00 p.m.

Wednesday, June 10, 1987

Chairman: James C. Wiltse, Georgia Tech Research Institute

S-1 (Invited) 1:30 p.m.	Millimeter Wave Material Properties and Measurements G.J. Simonis U.S. Army Harry Diamond Laboratories Adelphi, MD	747
S-2 (Invited) 1:50 p.m.	Advances in HEMT Technology and Applications P.M. Smith, P.C. Chao, K.H.G. Duh, L.F. Lester B.R. Lee and J.M. Ballingall General Electric Co. Syracuse, NY	749
S-3 (Invited) 2:10 p.m.	Imaging Antenna Arrays D. Rutledge California Institute of Technology Pasadena, CA	*
S-4 (Invited) 2:30 p.m.	GaAs Schottky Barrier Diodes for High Sensitivity Millimeter and Submillimeter Wavelength Receivers T.W. Crowe and R.J. Mattauch University of Virginia Charlottesville, VA	753

<sup>\*</sup>Manuscript not available at the time of printing

## **Session T**

### Ziefeld Room: Invited European Session

3	:30	p.m.	to	5:00	p.m.
•	•••	D	-		-

Wednesday, June 10, 1987

Chairman: R. Sparks, Raytheon

T-1 (Invited)	Detection of Millimeter and Submillimeter Waves	759
3:30 p.m.	E. Kollberg	
-	Chalmers University of Technology	
	Gothenburg, Sweden	
T-2 (Invited)	State-of-the-Art of MMIC Technology and Design in West Germany	763
4:00 p.m.	E. Pettenpaul	
	Siemens AG	
	Munich, West Germany	
T-3 (Invited)	Modeling of New Microwave Devices	767
4:30 p.m.	G. Salmer	
	Université de Lille	
	France	¥

### **Session U**

# Gable 5, 6, 7 Room: Waveguide Discontinuity Structures 3:30 p.m. to 5:00 p.m. Wednesday, June 10, 1987

Chairman: James W. Mink, U.S. Army Research Office

U-1 3:30 p.m.	A Dynamic Model for Microstrip – Slotline Transition and Related Structures HY. Yang and N.G. Alexopoulos Electrical Engineering Department University of California Los Angeles, CA	773
U-2 3:50 p.m.	Characterization of Stripline Crossing by Transverse Resonance Analysis T. Uwano Matsushita Electric Co. Osaka, Japan R. Sorrentino University of Rome Tor Vergata Roma, Italy and T. Itoh University of Texas Austin, TX	777
U-3 4:10 p.m.	An Improved Multimode Small Aperture/Obstacle Theory M. Guglielmi and A.A. Oliner Polytechnic University Brooklyn, NY	781
U-4 4:30 p.m.	An Accurate Analysis of Discontinuities in Dielectric Rectangular Waveguide and its Application to Grating Filters  M. Tsuji and H. Shigesawa Department of Electronics Doshisha University Kyoto, Japan	785
U-5 4:50 p.m.	Variational Bound Analysis of a Discontinuity in Nonradiative Dielectric Waveguide J.C. Olivier and J.A.G. Malherbe University of Pretoria South Africa	789

## **Session V**

## Gable 3, 4 Room: Microwave Acoustics: Developments & Applications 3:30 p.m. to 5:00 p.m. Wednesday, June 10, 1987

Chairman: Ted Lukaszek, U.S. Army Labcom

V-1 3:30 p.m.	Applications of Custom SAW Devices  Ronald C. Rosenfeld  Sawtek Inc.	*
	Orlando, FL	
V-2	Evolution of SAW Technology from Discrete Devices to	
3:50 p.m.	Functional RF Building Blocks	793
	H.G. Vollers and D. L. Ash	
	RF Monolithics	
	Dallas TX	
V-3	Miniature SAW Antenna Duplexer for Portable Telephone	797
4:10 p.m.	M. Hikita, Y. Ishica, T. Tabuchi and H. Kojima	
_	Central Research Laboratory	20
	Hitachi, Ltd.	
	Tokyo, Japan	
	and K. Kurosawa	
	Hitachi Toukai Works	
	Katsuta, Japan	
V-4	Design and Evaluation of UHF Monolithic Film	
4:20 p.m.	Resonator-Stabilized Oscillators and Bandpass Filters	801
	M.M. Driscoll, R.A. Moore, J.F. Rosenbaum	
	Westinghouse Defense and Electronics Center	
	Baltimore,MD	
	and S.V. Krishnaswami, and J.R. Szedon	
	Westinghouse Research and Development Center	
	Pittsburgh, PA	
V-5	Performance of Acoustic Charge Transport Chirp Filters	805
4:40 p.m.	F. Fiegel, R. Martin, and F. Guedin	
_	Electronic Decisions, Inc.	

Urbana, IL

<sup>\*</sup>Manuscript not available at the time of printing

#### **Session W**

## Gable 3, 4 Room: – Focused Session – Optical Techniques for Microwave Applications I

Chairman: Tatsuo Itoh, University of Texas, Austin

8:30 a.m. to 10:00 a.m.

Thursday, June 11, 1987

W-1 (Invited) Optical Generation and Control of Microwaves and 8:30 a.m. Millimeter-Waves 811 C.H. Lee Department of Electrical Engineering University of Maryland College Park, MD W-2 Microwave Performance of an Optically Controlled AIGaAs/GaAs 9:00 a.m. **High Electron Mobility Transistor and GaAs MESFET** 815 R.N. Simons NRC-NASA Research Associate Cleveland, OH and K.B. Bhasin NASA Lewis Research Center Cleveland, OH W-3 A High-Speed Phase Shifter Based on Optical Injection 819 L.R. Brothers and C.H. Cox, III 9:20 a.m. MIT Lincoln Laboratory Lexington, MA Phase and Frequency Coherency of Multiple Optically W-4 Synchronized 20 GHz FET Oscillators For Satellite 9:40 a.m. **Communications** 823 A.S. Daryoush, P.R. Herczfeld, R. Glatz Department of Electrical and Computer Engineering

Drexel University, Philadelphia, PA

and A.P.S. Khanna

Avantek, Santa Clara, CA

## **Session X**

#### Ziegfeld Room: FET Amplifiers

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#### Thursday, June 11, 1987

Chairman: Eliot D. Cohen, Defense Logistics Agency

X-1 8:30 a.m.	Design and Performance of a New Multi Octave High-Gain Amplifier  K.B. Niclas, R.R. Pereira, A.J. Graven and A.P. Chang Watkins-Johnson Company Palo Alto, CA	829
X-2 8:50 a.m.	A High Performance, Quasi-Monolithic 2-18GHz Distributed GaAs FET Amplifier  A. Cappello, T. Alexander, J. Calviello, D. Ward, P. Bié and R. Pomian  Eaton Corporation/AIL Division  Melville, NY	833
X-3 9:00 a.m.	Operating Characteristics of 2-8 GHz GaAs MESFET Amplifiers at Elevated Case Temperatures to 200 Degrees Centigrade E.J. Crescenzi, Jr., J.A. Thompson, T.R. Kritzer and M.E. Kretschmar Watkins-Johnson Co. Palo Alto, CA	837
X-4 9:20 a.m.	A 6-18 GHz MMIC Power Amplifier Module Designed for Automated Assembly Fabrication* C.A. Sapashe, D.L. Green, C.D. Palmer, and J.S. Pavio Texas Instruments Dallas, TX	841
X-5 9:30 a.m.	A 6 Watt Power GaAs FET for 14.0-14.5 GHz Band Y. Kadowaki, S. Igi, M. Wataze, T. Sonoda, K. Hayashi, M. Yamanouchi, S. Takamiya and S. Mitsui Mitsubishi Electric Corporation Hoyogo, Japan	845
X-6 9:40 a.m.	K- and Ka-Band High Efficiency Amplifier Modules Using GaAs Power FETs D. Bechtle, J. Klatskin, G. Taylor, M. Eron, S.G. Liu, R. Camisa and H. Dudley David Sarnoff Research Center	849

Princeton, NJ

### **Session Y**

### Gable 5, 6, 7 Room: Solid State Devices/Circuits I 8:30 a.m. to 10:00 a.m. Thursday, June 11, 1987

Chairman: Michael Dydyk, Motorola

Y-1 8:30 a.m.	Silicon Bipolar MMIC for Frequency-Conversion Application up to 20 GHz  L. Kipnas Avantek, Inc. Santa Clara, CA	855
Y-2 8:50 a.m.	Frequency Stability of L-Band Two-Port Dielectric Resonator Oscillators M. Loboda, T.E. Parker, and G.K. Montress Raytheon Research Division Lexington, MA	859
Y-3 9:10 a.m.	Solid State MM-Wave Oscillators with Large Tuning Range K. Jacobs, and B. Vowinkel University of Cologne West Germany	863
Y-4 9:20 a.m.	Varactor-Tuned Microstrip Ring Resonators K. Chang, S. Martin, and F. Wang Department of Electrical Engineering Texas A & M University College Station, TX	867
Y-5 9:40 a.m.	A Multi-Diode Cavity Power Combiner Using State-of-the-Art Pulsed Gunn Diodes B.E. Sigmon Motorola Government Electronics Group Tempe, AZ and M. Ayyagari MA/COM Semiconductor Burlington, MA	871

## **Session Z**

## Gable 3, 4 Room: – Focused Session –

#### **Optical Techniques for Microwave Applications II**

10:30 a.m. to Noon

Thursday, June 11, 1987

Chairman: N.R. Dietrich, AT&T Labs

Z-1 (Invited) 10:30 a.m.	Microwave Measurements of GaAs Integrated Circuits Using Electrooptic Sampling K.J. Weingarten, R. Majidy-Aky, M.J.W. Rodwell, D.M. Bloom and B.A. Auld Stanford University Stanford, CA	877
Z-2 11:00 a.m.	Picosecond Reflectometry Technique for On-Chip Characterization of Millimeter-Wave Semiconductor Devices C. Rauscher Naval Research Laboratory Washington, DC	881
Z-3 11:20 a.m.	Direct Fiber Optic Transmission of a Wideband Multi-Carrier Microwave Signal Spectrum to and from Satellite Earth Station Antennas J.W. Carlin, J.E. Bowers, A.C. Chipaloski and S. Boodaghians AT&T-Bell Laboratories Holmdel, NJ	885
Z-4 11:40 a.m.	Optical Feedback on Linearity Performance of 1.3 $\mu m$ DFB and Multimode Lasers Under Deep Microwave Modulation W.I. Way and M.M. Choy Bell Communications Research Red Bank, NJ	889

## **Session AA**

## Ziegfeld Room: Non-Linear FET Applications

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Sunnyvale, CA

Thursday, June 11, 1987

Chairman: E.C. Niehenke, Westinghouse Electric Corp.

AA-1 10:30 a.m.	A GaAs MESFET Balanced Mixer with Very Low Intermodulation Stephen A. Maas The Aerospace Corp. Los Angeles, CA	895
AA-2 10:50 a.m.	A Monolithic Double Balanced Single Sideband Modulator S.D. Thompson and A.M. Pavio Texas Instruments, Inc. Dallas, TX	899
AA-3 11:10 a.m.	Passive GaAs FET Switch Models and their Application in Phase Shifters L.C. Upadhyayula, R.L. Camisa, G. Taylor, S.N. Subbarao and S.G. Liu RCA Laboratories Princeton, NJ	903
AA-4 11:20 a.m.	A Non-Linear Design and Optimization Procedure for GaAs MESFET Oscillators  T.J. Brazil and J.O. Scanlan Department of Electrical Engineering University College Dublin, Ireland	907
AA-5 11:40 a.m.	High Performance GaAs C-Band and Ku-Band MMIC Oscillators S. Moghe and T. Holden Pacific Monolithics, Inc.	911

## **Session BB**

#### Gable 5, 6, 7 Room: Solid State Devices/Circuits II

10:30 a.m. to Noon

Boulder, CO

Thursday, June 11, 1987

Chairman: Clifford Krowne, Naval Research Lab

BB-1 10:30 a.m.	Multi-Watt Power Generation at Millimeter-Wave Frequencies Using Epitaxially-Stacked Varactor Diodes P.W. Staecker, M.E. Hines, F. Occhiuti and J.F. Cushman M/A Com Inc. Burlington, MA	917
BB-2 10:50 a.m.	A New Reversible Varactor Frequency Halver/Double Device Z. Nativ Rafael State of Israel Armament Development Authority Haifa, Israel	921
BB-3 11:10 a.m.	Measurements and Modeling of Kinetic Inductance Microstrip Delay Lines J.M. Pond, J.H. Claasen and W.L. Carter Naval Research Laboratory Washington, DC	925
BB-4 11:30 a.m.	A 100 GHz SIS Quasiparticle Mixer with 10 DB Coupled Gain A.V. Raisanen, D.C. Crete, P.L. Richards and F.L. Lloyd* Department of Physics University of California Berkeley, CA *National Bureau of Standards	929

## **Session CC**

# Gable 3, 4 Room: Phased and Active Array Techniques 1:30 p.m. to 3:00 p.m. Thursday, June 11, 1987

Chairman: Eugene H. Gregory, Hughes Aircraft Co.

CC-1 1:30 p.m.	A 2 Watt GaAs TX/RX Module with Integral Control Circuitry, For S-Band Phased Array Radars C.R. Green, A.A. Lane, P.N. Tombs, R. Shukla, P.D. Cooper J.R. Suffolk, and J.A. Sparrow Plessey Research Caswell Ltd. Caswell, UK	933
CC-2 1:50 p.m.	A 35 GHz Electronically Steered Line Array R.J. Lang and B.J. Edward General Electric Company Syracuse, NY	937
CC-3 2:10 p.m.	An Ultraminiature 5-10 GHz, 2 Watt Transmit Module for Active Aperture Application J. Pierro and R. Clouse Eaton Corp./AIL Division Melville, NY	941
CC-4 2:30 p.m.	Microstrip FED Planar Frequency Multiplying Space Combiner S. Nam, T. Uwano, and T. Itoh Department of Electrical and Computer Engineering University of Texas Austin, TX	945
CC-5 2:40 p.m.	Low Cost Cartop Phased Array Steering G. Schaffner Teledyne Ryan Electronics San Diego, CA	949

## **Session DD**

## **Ziegfeld Room: HEMT/MESFET Applications**

1:30 p.m. to 3:00 p.m.

Thursday, June 11, 1987

Chairman: B.D. Geller, Comsat Corporation

DD-1 1:30 p.m.	Bias-Dependent Microwave Characteristics of an Atomic Planar-Doped A1GaAs/InGaAs/GaAs Double Hetrojunction MODFET Y.K. Chen, D.C. Radulescu, G.W. Wang, A.N. Lepore, P.J. Tasker and L.F. Eastman School of Electrical Engineering Cornell University Ithaca, NY	*
DD-2 1:50 p.m.	FETs and HEMTs at Cryogenic Temperatures – Their Properties and Use in Low-Noise Amplifiers M.W. Pospieszalski and S. Weinreb National Radio Astronomy Observatory Charlottesville, VA	955
DD-3 2:10 p.m.	Reliability of Low-Noise Microwave HEMT Using by MOCVD K. Tanaka, H. Takakuwa, K. Togashi, Y. Kato and S. Watanabe Sony Corp. Kanagawa, Japan	*
DD-4 2:20 p.m.	Predicting Long Term Frequency Drift in FET Oscillators Using Device Modeling K.K. Agarwal and C. Ho Telecommunication Division Rockwell International Corp. Dallas, TX	959
DD-5 2:40 p.m.	Harmonic Reaction Amplifier – A Novel High-Efficiency and High-Power Microwave Amplifier  S. Nishiki and T. Nojima  NTT Electrical Communications Laboratories  Take Yokosuka-Shi, Kanagawa-Ken, Japan	963

<sup>\*</sup>Manuscript not available at the time of printing

## **Session EE**

## Gable 5, 6, 7 Room: Solid State Devices/Circuits III 1:30 p.m. to 3:00 p.m. Thursday, June 11, 1987

Chairman: Robert L. Eisenhart, Hughes Aircraft Co.

EE-1 1:30 p.m.	A1GaAs/GaAs Heterojunction Bipolar Transistors with 4W/mm Power Density at X Band B. Bayraktaroglu, N. Camilieri, H.D. Shih, and H.G. Tserng Texas Instruments Dallas, TX	969
EE-2 1:50 p.m.	Millimeter Wave Heterojunction MITATT Diodes N.S. Dogan, J.R. East Department of Electrical Engineering Washington State University Pullman, WA M.E. Elta and G.I. Haddad The University of Michigan Ann Arbor, MI	973
EE-3 2:10 p.m.	Improved Performance of Fundamental and Second Harmonic MMW Oscillators Through Active Device Doping Concentration Contouring J. Ondria Marconi Electronic Devices Ltd Lincoln, England and R.L. Ross U.S. Army Electronic Technology and Devices Laboratory Fort Monmouth, NJ	977
EE-4 2:30 p.m.	W-Band Microstrip Oscillator Using InP Gunn Diode D.R. Singh Defense Systems Division Honeywell Inc.	981

Minnetonka, MN

#### Session FF

#### Gable 3, 4 Room: Microwave Ferrites

	3:30	p.m.	to	5:00	p.m.
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Thursday, June 11, 1987

Chairman: W.E. Hord, Microwave Applications Group

FF-1 A New Type of Fast Switching Dual-Mode Ferrite Phase Shifter 985 3:30 p.m. W.E. Hord, C.R. Boyd, Jr. and D. Diaz Microwave Applications Group Santa Maria, CA FF-2 Impact of Dielectric Loss Tangent on the Performance of 3:50 p.m. Millimeter Wave Ferrite Circulators 989 G.R. Harrison, S.B. Thompson, J.T. Vaughn Electromagnetic Sciences, Inc. Norcross, GA and G.P. Rodrigue School of Electrical Engineering Georgia Institute of Technology Atlanta, GA FF-3 Full Wave Analysis of Slot Line and Coplanar Waveguide on a 4:00 p.m. **Magnetic Substrate** 993 E. El-Sharawy and R.W. Jackson University of Massachusetts Amherst, MA FF-4 Magnetostatic Waves in a Normally Magnetized Waveguide Structure 997 4:10 p.m. M. Radmanesh GMI Engineering & Management Institute Flint, MI and C.M. Chu and G.I. Haddad University of Michigan Ann Arbor, MI 1001 FF-5 **Energy Storage Effect in MSSW Metal-Finger Reflectors** T.S. Cheng 4:20 p.m.

Bell Communications Research

Red Bank, NJ

and J.P. Parekh and H.S. Tuan

Department of Electrical Engineering

State University of New York

Stony Brook, NY

### **Session GG**

### Gable 5, 6, 7 Room: HEMT Amplifiers and Devices

Chairman: Bert Berson, Berson & Associates

3:30 p.m. to 5:00 p.m.

Thursday, June 11, 1987

GG-1 3:30 p.m.	HEMT Low-Noise Amplifier for Ka-Band M.A.G. Upton, P.M. Smith and P.C. Chao General Electric Co. Syracuse, NY	1007
GG-2 3:50 p.m.	Broadband HEMT Amplifier for 26.5-40 GHz K. Shibata, B. Abe, S. Hori and K. Kamei Toshiba Corporation Kawasaki, Japan	1011
GG-3 4:10 p.m.	A Four Stage V-Band MOCVD HEMT Amplifier W. Yau, E.T. Watkins, S.K. Wang, K. Wang and B. Klatskin Hughes Aircraft Company Torrance, CA	1015
GG-4 4:30 p.m.	Super Low-Noise HEMTs with a T-Shaped Gate Structure S. Asai, K. Joshin, Y. Hirachi and M. Abe Fujitsu Laboratories Ltd. Atsugi, Japan	1019

1023

4:40 p.m. K. Hayashi, T. Sonoda, T. Yamaguchi, K. N S. Mitsui, and M. Yamanouchi Mitsubishi Electric Corp.

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Itami, Japan